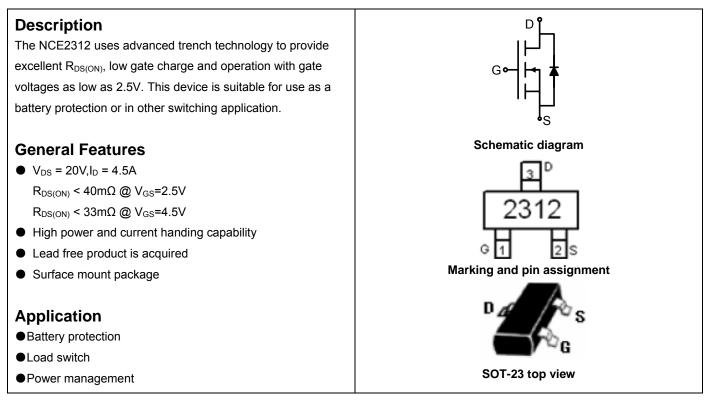




NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

U	0	<u> </u>			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2312	NCE2312	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Paramete	Symbol	Limit	Unit	
Drain-Source Voltage		Vds	20	V
Gate-Source Voltage		Vgs	±12	V
Continuous Drein Current	T _A =25℃	1	4.5	^
Continuous Drain Current	T_A =70 ℃	– I _D	3.6	A
Drain Current-Pulsed (Note 1)	I _{DM}	15	A	
Maximum Power Dissipation		PD	1.25	W
Operating Junction and Storage Temperature Range		T_J,T_STG	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ extsf{ heta}JA}$	100	°C/W

Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	20	21.5	-	V



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Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	0.5	0.65	1.0	V
Drain Source On State Desistance	R _{DS(ON)}	V _{GS} =2.5V, I _D =4.0 A	-	21	40	mΩ
Drain-Source On-State Resistance		V _{GS} =4.5V, I _D =4.5A	-	18	33	mΩ
Forward Transconductance	g fs	V _{DS} =10V,I _D =4A	-	10	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	Clss		-	500	-	PF
Output Capacitance	Coss	$V_{DS}=8V, V_{GS}=0V,$	-	295	-	PF
Reverse Transfer Capacitance	Crss	– F=1.0MHz	-	96	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t _{d(on)}		-	11	-	nS
Turn-on Rise Time	tr	V _{DD} =10V,I _D =1A	-	30	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =4.5V, R_{GEN} =6 Ω	-	35	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg		-	10	15	nC
Gate-Source Charge	Q _{gs}	V _{DS} =10V,I _D =3A,V _{GS} =4.5V	-	2.3	-	nC
Gate-Drain Charge	Q _{gd}		-	2.9	-	nC
Drain-Source Diode Characteristics					•	•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =1A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	4.5	Α

Notes:

- **1.** Repetitive rating: pulse width limited by maximum junction temperature.
- **2.** Surface mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse test: pulse width \leq 300µs, duty cycle \leq 2%.
- 4. Guaranteed by design, not subject to production





NCE2312

Typical Electrical and Thermal Characteristics

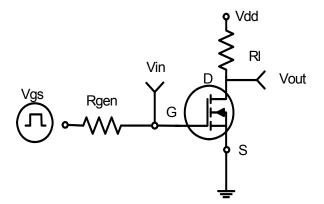


Figure 1:Switching Test Circuit

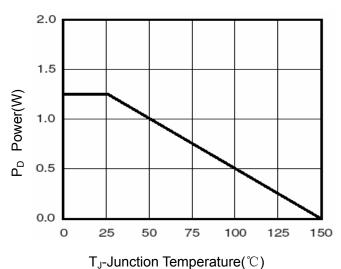
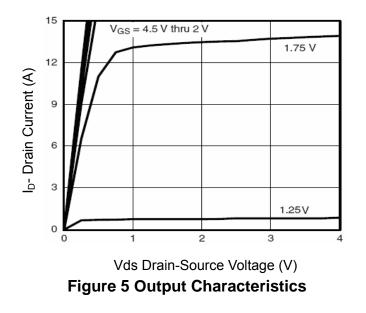


Figure 3 Power Dissipation



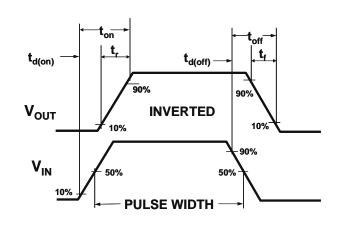
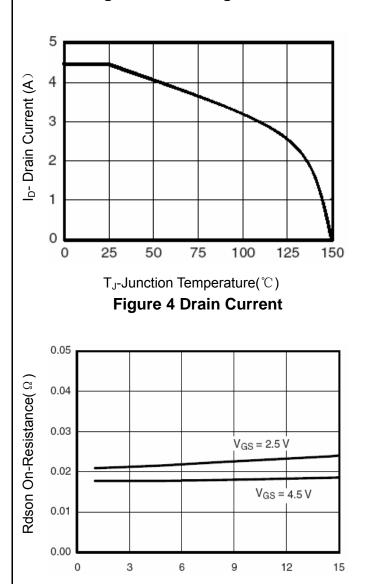


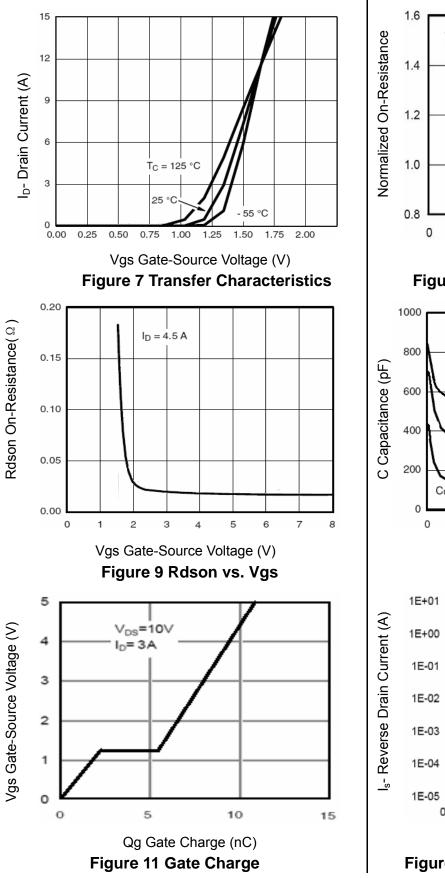
Figure 2:Switching Waveforms

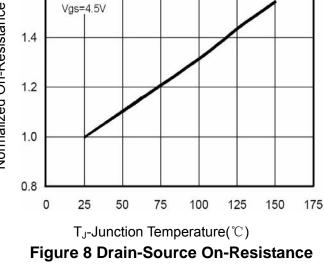


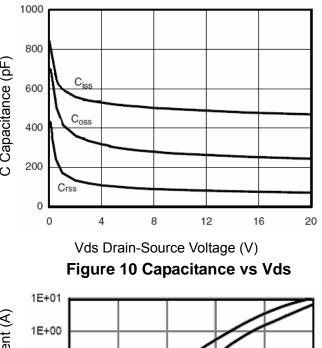
I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance



NCE2312







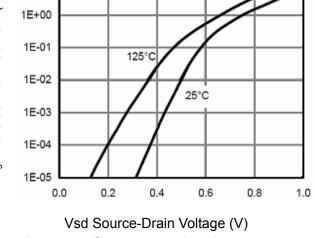
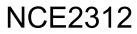
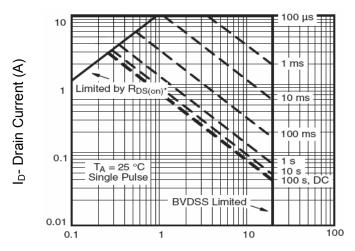


Figure 12 Source- Drain Diode Forward









Vds Drain-Source Voltage (V)

Figure 13 Safe Operation Area

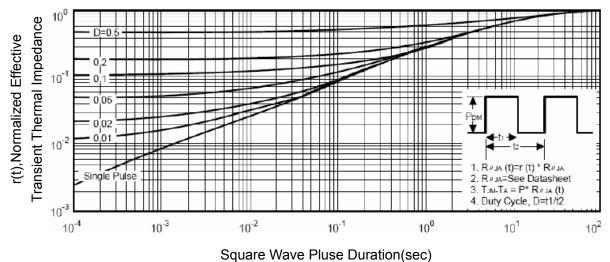
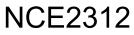
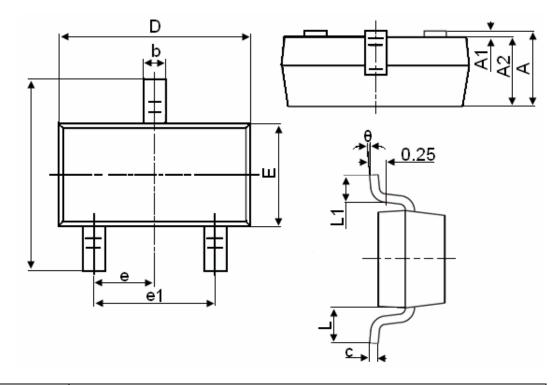


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

1. All dimensions are in millimeters.

2. Tolerance ± 0.10 mm (4 mil) unless otherwise specified

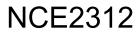
3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.

4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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